NSN 5962-01-324-5168

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View Online at https://aerobasegroup.com/nsn/5962-01-324-5168

Body Length:

Between 0.484 inches and 0.496 inches

Body Width:

Between 0.284 inches and 0.296 inches

Body Height:

Between 0.064 inches and 0.078 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and static operation and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

19 input

Current Rating Per Characteristic:

50.00 milliamperes forward current, peak total value not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Memory Device Type:

Ram

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

22 flat leads

Specification Data:

81349-mil-m-38510/292 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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